Towards the modelling of the self-assembly of metal clusters on graphene epitaxied on metals

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Introduction and background

In epitaxial graphene on metal (GOM), the lattice mismatch between the two materials gives rise to periodic moiré superstructures. The resulting corrugation may act as a template for well-ordered arrays of magnetic nanoclusters with promising applications in high-density storage devices. The use of atomistic simulations enables us to study large systems that are currently inaccessible to DFT. Here we focus on the archetypal case of ruthenium for which a wealth of experimental and DFT data are available.^[1,2]

Experimental STM measurements^[1]



(a) Graphene on Ir(111): moiré superstructure. (b) Ir clusters deposited on GOM

Goals

• Investigate the stability of deposited clusters

• Study of dynamical effects at finite temperature Methods

- Assess different Bond-order Potentials (BOPs) by NPT Monte Carlo simulations for pristine graphene
- Adjust Brenner BOP parameters for metal-metal and carbon-metal interactions to experimental and DFT data, respectively
- Study moiré geometry for various inplane angles between graphene and metal substrate

Bond-order potentials

Suitable to highly coordinated material, BOPs contains a built-in correlation between coordination and bond strength:



- $V_R(\mathbf{r}_{ij})$, $V_A(\mathbf{r}_{ij})$: Interatomic repulsive and attractive pair functions, respectively
 - : Bond-order, depends on the local coordination and bond angles

The performances of three different BOPs are assessed for pristine graphene:

- **Brenner's BOP**^[3] : Interactions only between first neighbours
- $LBOP^{[4]}$: Brenner's BOP including long-range interactions
- LCBOP^[5] : BOP including long-range interactions, with a bond-order expression especially

Graphene

Thermal excitation causes corrugation of graphene.^[13] Consequently, increase of temperature induces the inplane lattice parameter a to decrease, which reflects in a negative thermal expansion coefficient $\alpha(T)$.





- Average bond distances $d_{\rm CC}$ increases with temperature: usual behaviour of classical solids
- Minor effects of simulation cell sizes
- BOP and LBOP present contraction of *a* in qualitative agreement with DFT^[6-8] but overestimate *a* over a large temperature range
- Only LCBOP exhibits an increase in a near 700 K although it is

Thermal expansion coefficient



• Qualitative agreement of BOP and LBOP with references [6-8,11,12] Qualitative agreement of LCBOP with references [9,10]

• Sign of $\alpha(T)$ not consistent throughout literature (open question)

Remarks

Monte Carlo NPT simulations at P=0 reveal that various BOPs exhibit discrepancies in d_{CC} , a and $\alpha(T)$ depending on the potential used.

Deviation from harmonic (bending) to anharmonic (stretching) coupling modes has been proposed to explain the sign change of $\alpha(T)$.^[13] However this has been questioned by a recent approach based on classical elasticity theory.^[14]

All BOPs present a qualitative agreement with DFT below 700 K in a

Graphene on metal

Atomistic potential and its parameters for graphene on Ru(0001)

Pure carbon

Β_{ij}

• Brenner BOP^[3] with original parameters

Pure ruthenium

- Embedded Atom Model (EAM), form as in Cleri and Rosato^[15]
- Additional dispersion force correction for semi-infinite substrate
- Parameters for Ru adjusted via Monte Carlo fit to experimental data
- Reproduced quantities: lattice constants, cohesive energy, elastic constants
- Consistent description of the entire system by rewriting the EAM potential in the form of Brenner BOP

Ruthenium-Carbon

- Brenner BOP form plus a dispersion force correction for semi-infinite Ru substrate.
- Parameter adjustment via Monte Carlo fit of several equilibrium structures determined by DFT^[2]
- Match the zero forces

Moiré geometries for graphene on Ru(0001)

- The periodicity of the moiré superlattice is about one order of magnitude lower than the one of graphene
- In the case of graphene on Ru(0001) two types of moiré are relevant:
- -12 carbon atoms matching 11 ruthenium atoms
- -13 carbon atoms matching 12 ruthenium atoms
- An inplane angle between graphene and the Ru(0001) surface reduces the size of the moiré supercell a^* :



Graphene on Ru(0001), 12 carbon atoms Graphene on Ru(0001), 12 carbon atoms matching 11 ruthenium atoms: lattices matching 11 ruthenium atoms: inplane angle of 6.3 $^\circ$ aligned



Adsorption of clusters on GOM

• Energy minimum for adatom is located at hcp site of the moiré supercell

• The graphene sheet is closest to the metal surface at the hcp site



Interaction energy of a Ru adatom with the substrate throughout the moiré supercell

Preliminary result: Adsorption energy of Ru₅₅-cluster: -4.47 eV



- Reproduce adsorption energies of the graphene layer and adatoms

Quantity	DFT results	Reproduced values
Corrugation of graphene layer	1.44 Å	1.63 Å
Corrugation of topmost ruthenium layer	0.04 Å	0.23 Å
Smallest separation of graphene and topmost graphene layer	2.24 Å	2.12 Å
Average spacing of the uppermost metal layers	2.07 Å	2.14 Å
Adsorption energy of graphene layer	-3.9 eV	-3.88 eV
Interaction energy of graphene layer	-10.0 eV	-11.99 eV
Adsorption energy of an adatom at fcc site	-2.6 eV	-3.97 eV

Moiré supercell edge as function of inplane angle between graphene and Ru(0001) surface



*Ru*₅₅-cluster adsorbed on graphene on *Ru*(0001) at hcp site

Perspectives and future research

• Further improvement of the parameters for the potential: refine Monte Carlo fitting procedure using replica exchange

- Establish an equivalent potential for systems presenting a lower corrugation (graphene on lr(111))
- Relaxation of systems with adsorbed clusters
- Study of dynamics at finite temperature of individual and multiple clusters
- Replace the atomistic description of the cluster-substrate interaction by a continuous approximation

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